NSN 5961-01-115-5168

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View Online at https://aerobasegroup.com/nsn/5961-01-115-5168 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.175 inches and 0.205 inches **End Application:** Td-1159 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Terminal Circle Diameter:** 0.105 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 collector to emitter voltage/static/base open and 12.0 breakdown voltage, collector-to-emitter, base open and 4.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 80.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: